

Atmospheric Pressure Plasma Thin Film Deposition

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- Atmospheric Pressure Plasma Thin Film Deposition
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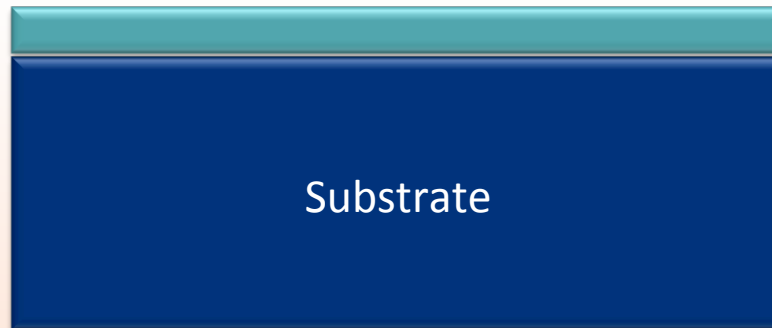
Introduction

- Thin Film Deposition
- Classify thin film deposition
- Application of Thin Film Deposition

Thin Film Deposition



Fractions of nm to
several μm



Thin Film Deposition

PVD : Physical Vapor Deposition

Thermal evaporation

DC or RF sputtering

Ion Beam sputtering

Pulsed Laser Deposition

Molecular beam epitaxy

CVD : Chemical Vapor Deposition

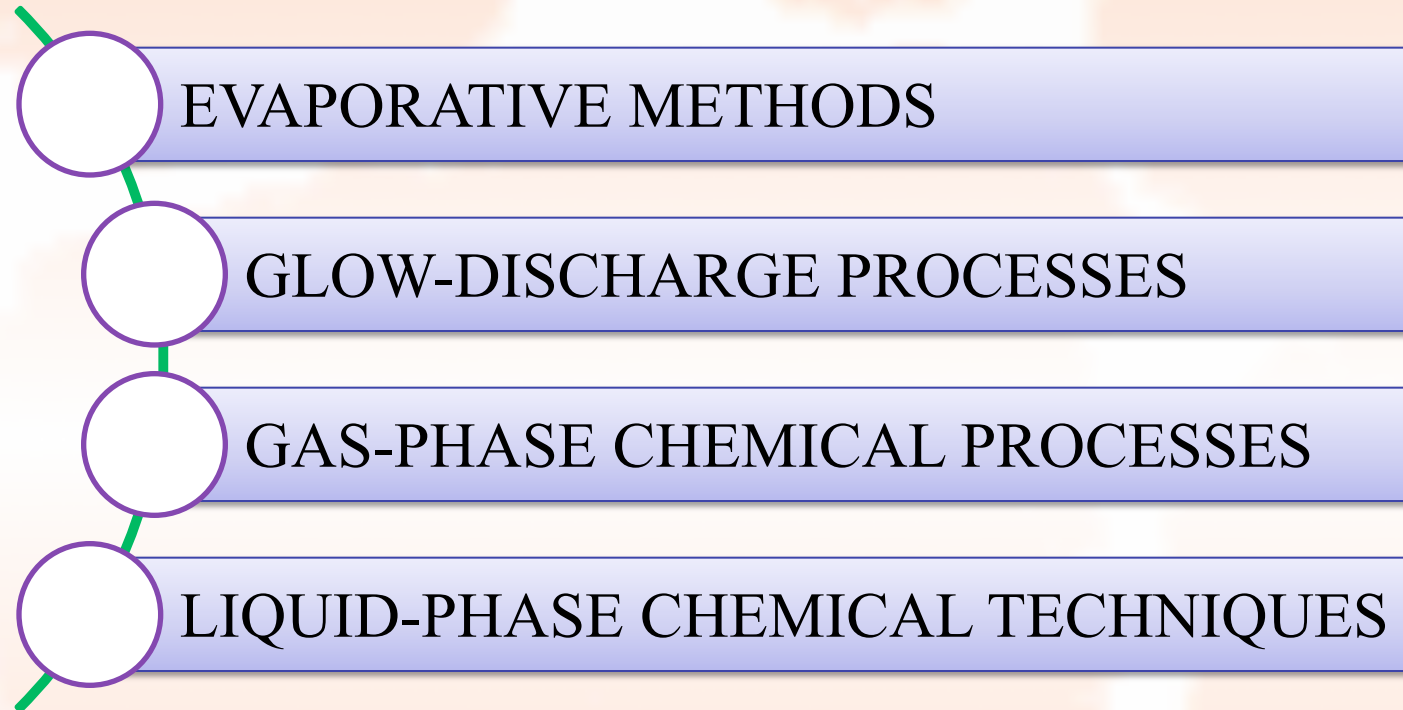
Thermal CVD

Low pressure CVD

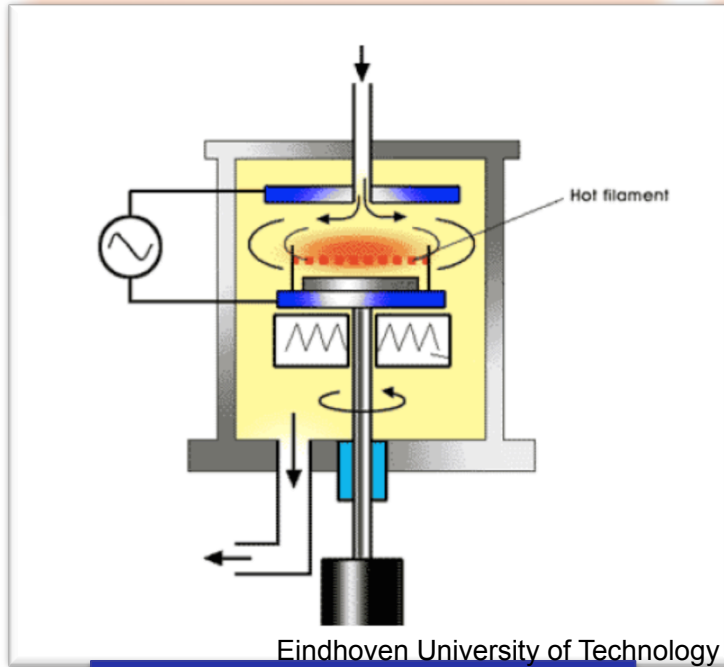
Plasma enhanced CVD

Metal-organic CVD

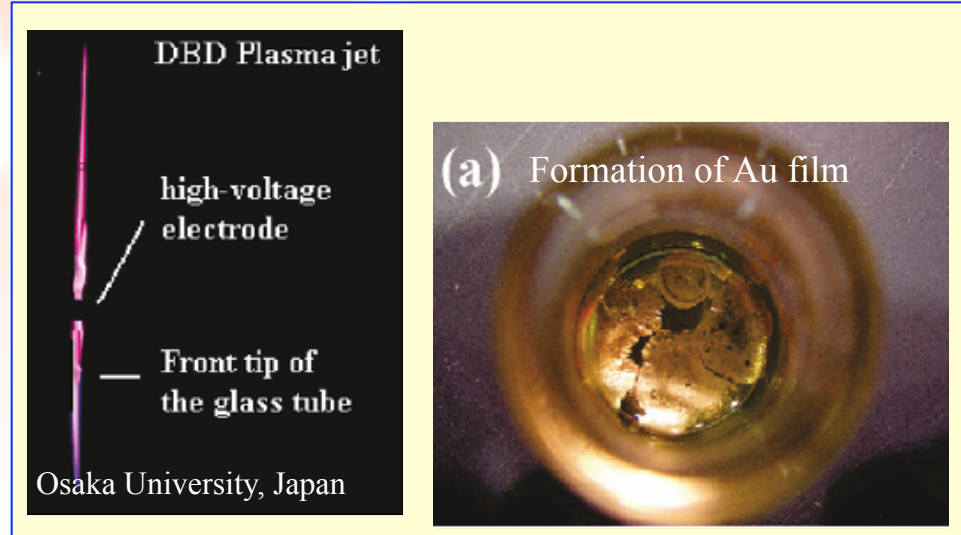
Thin Film Deposition Technology



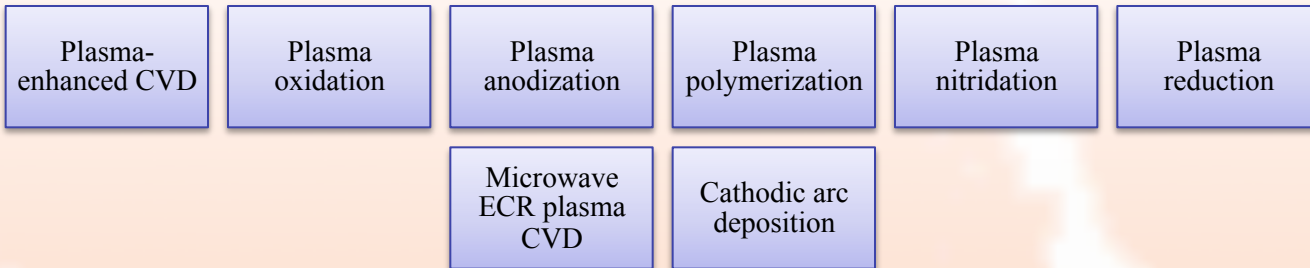
Plasma Processes in Thin Film Deposition



Plasma Enhanced CVD



Plasma reduction



Application of Thin Film Deposition



Electronic Components.



Electronic Displays



Optical Coatings.



Magnetic Films for Data Storage



Optical Data Storage Devices



Antistatic Coatings

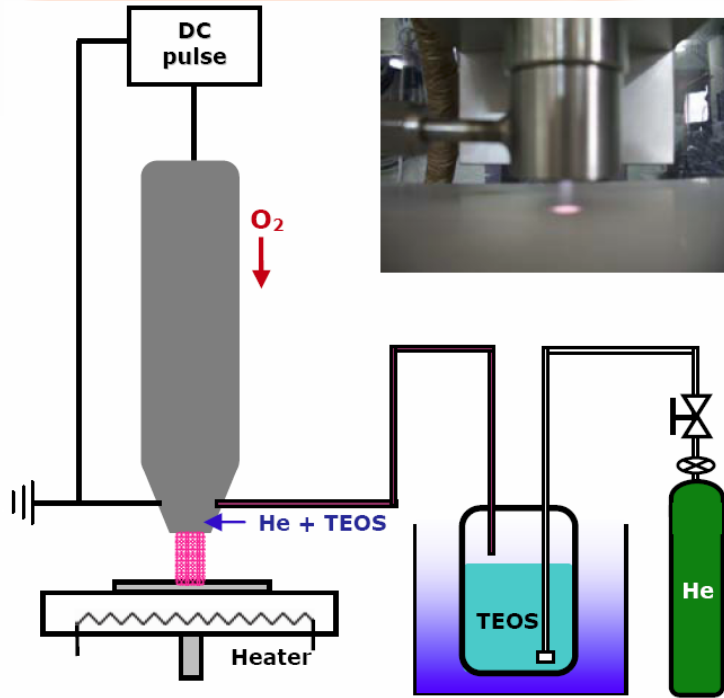


Hard Surface Coatings

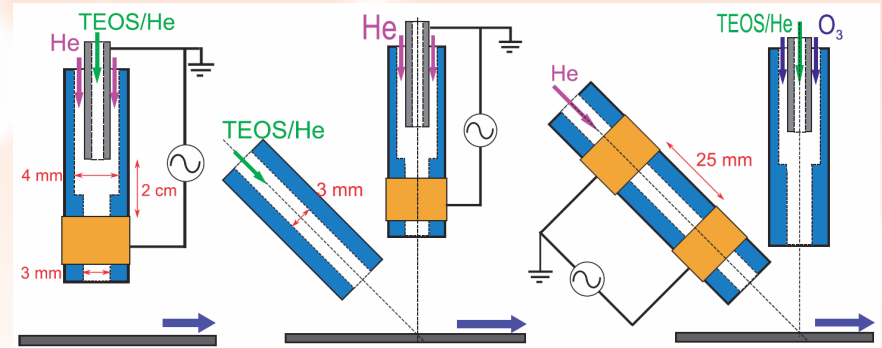
Atmospheric Pressure Plasma Thin Film Deposition

- Advantage
- Disadvantage
- Application of APPTFP

Atmospheric Pressure Plasma Thin Film Deposition



M. H. Han, et al



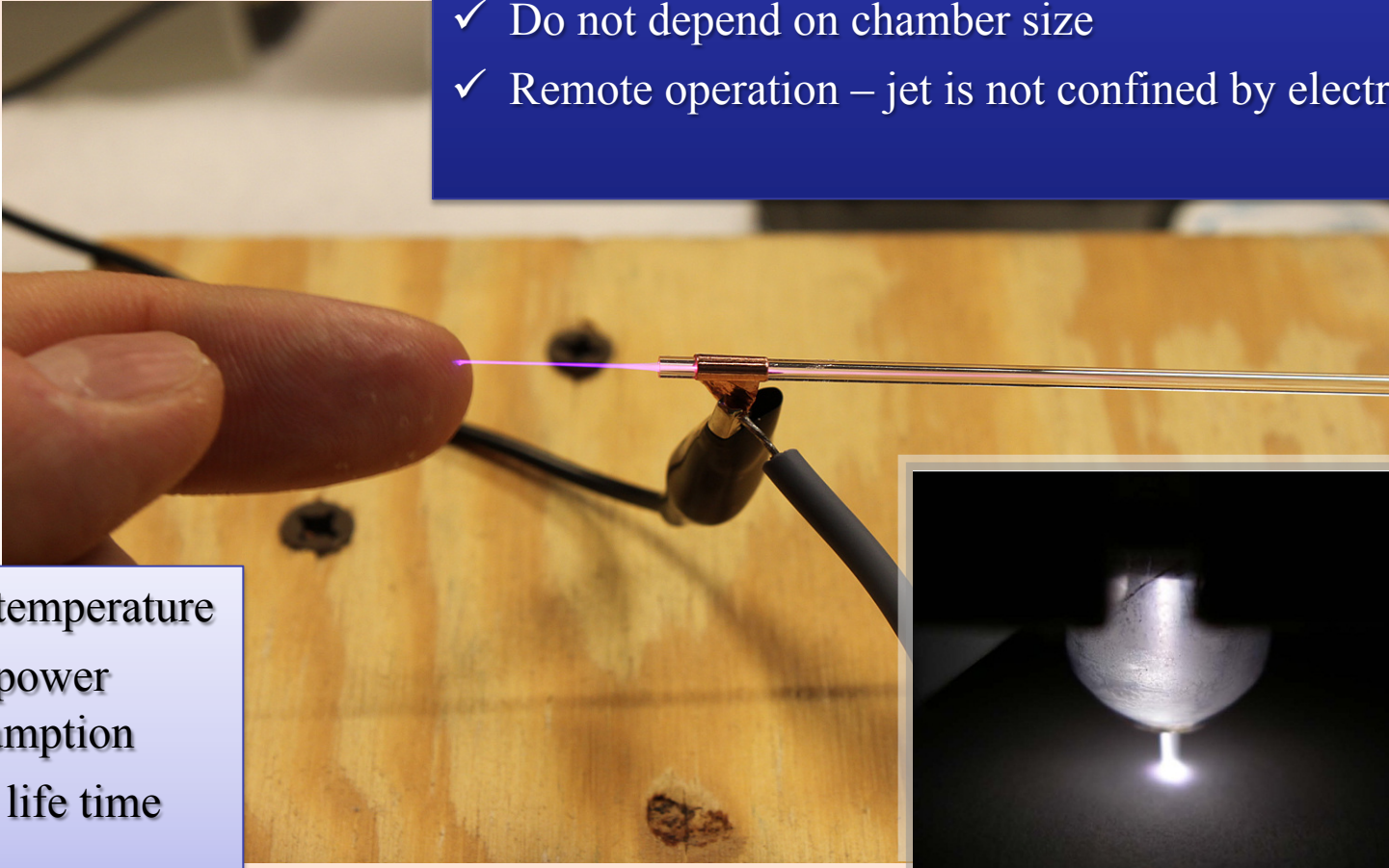
Y. Ito, K. Urabe, N. Takano, and K. Tachibana



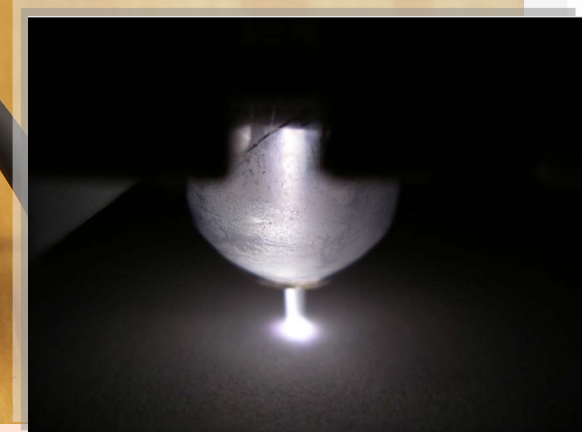
Chun Huang, Wen-Tung Hsu,...

Advantage

- ✓ Can use DC, radio frequency or microwave driven
- ✓ Simple structure
- ✓ Do not depend on chamber size
- ✓ Remote operation – jet is not confined by electrodes



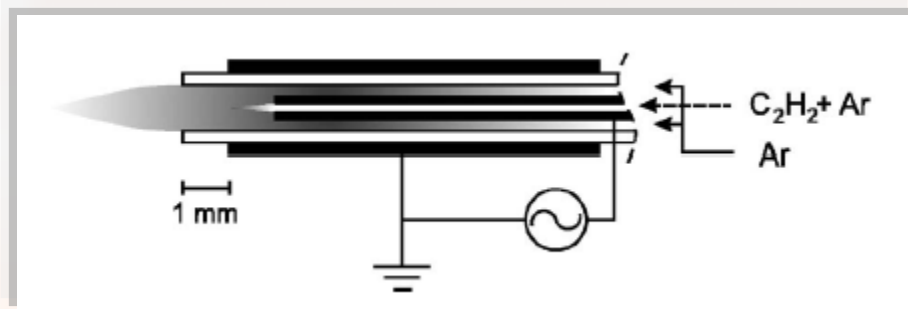
- ✓ Low temperature
- ✓ Low power consumption
- ✓ Long life time



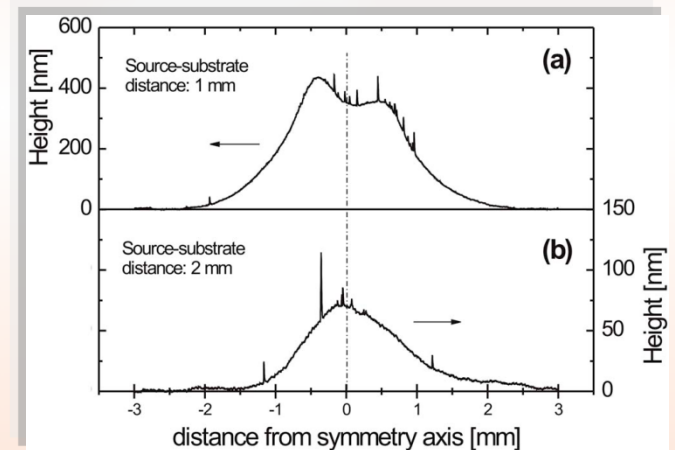
Disadvantage

- ✓ Miniature size
- ✓ Deposition or erosion of electrodes
- ✓ Contaminant
- ✓ Transport of reactive species is more complex than in the low pressure discharge

- ✓ Slow deposition rate
- ✓ not perfect equal height surface



M. Wolter, S. Bornholdt, M. Häckel, H. Kersten, Atmospheric pressure plasma jet for treatment of polymers, Journal of Achievements in Materials and Manufacturing Engineering 37/2 (2009) 730-734.



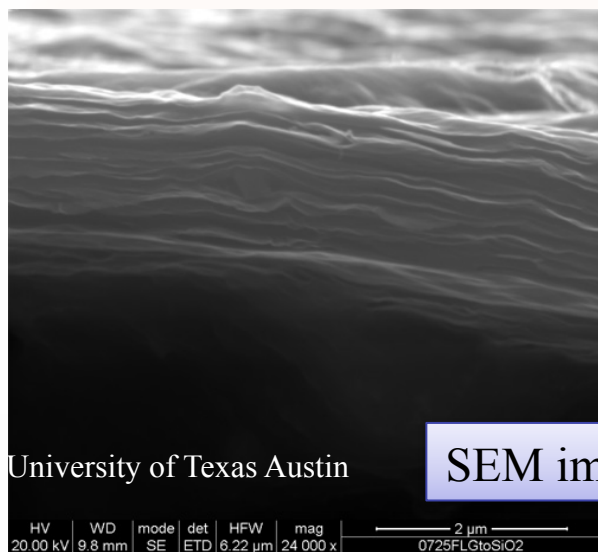
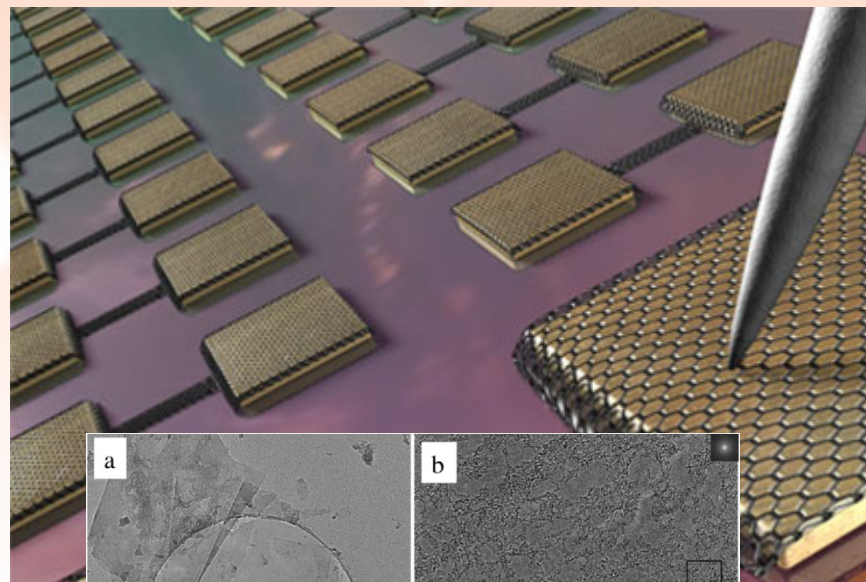
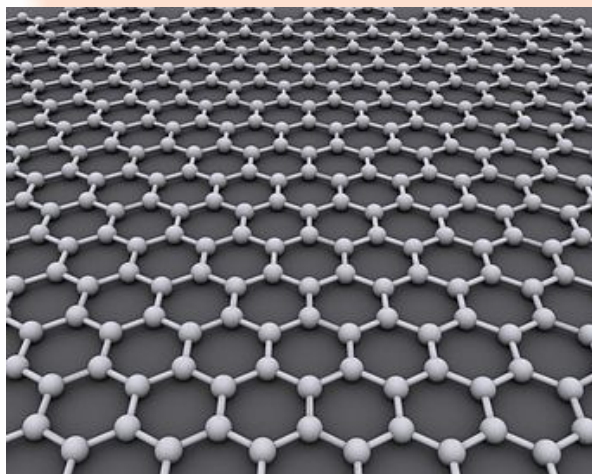
Application of APPTFP

- Suitable for the treatment of temperature-sensitive materials with melting point under 150°C
- Treatment of 3D surfaces, e.g. inner walls, trenches or cavities

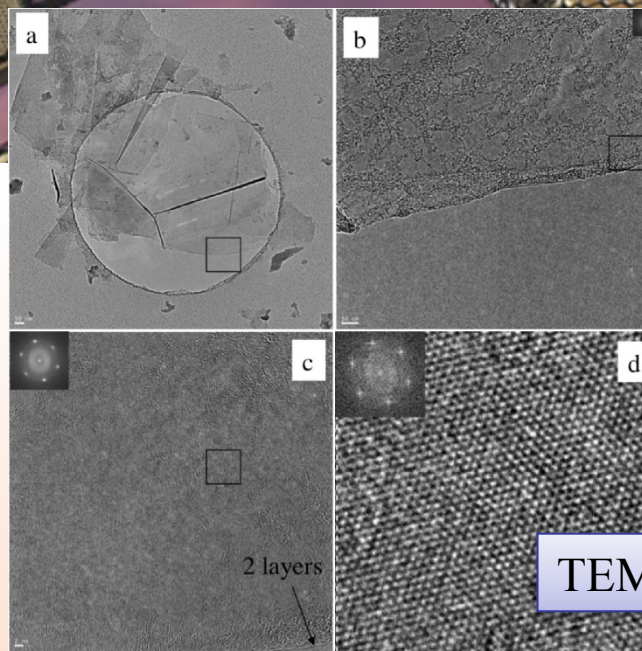
Research Approach

- Graphene & PMMA
- Proposal

Graphene

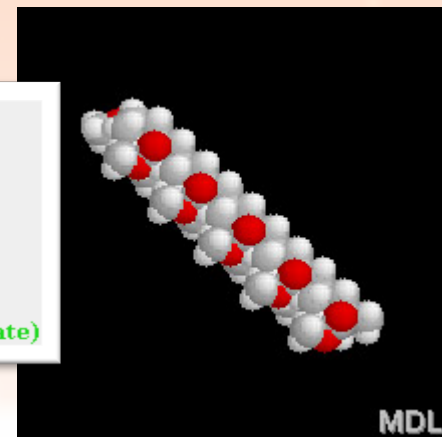
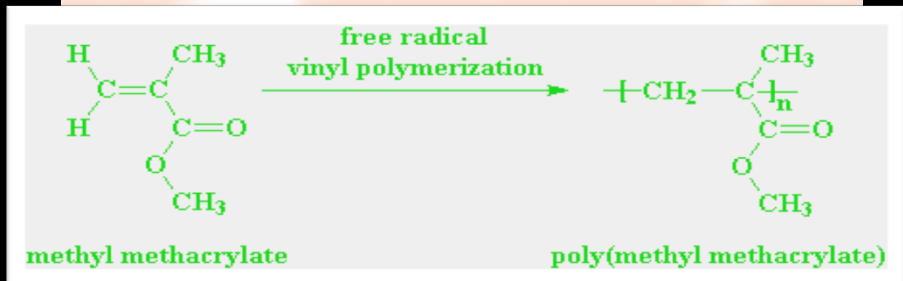
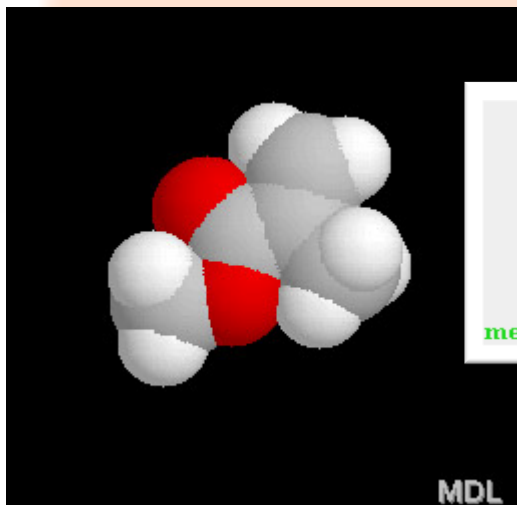


SEM image



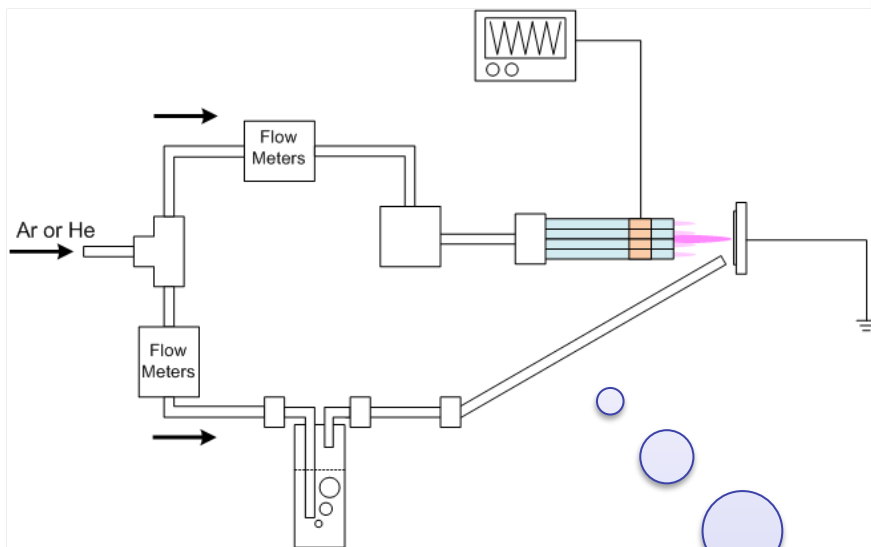
TEM image

PMMA

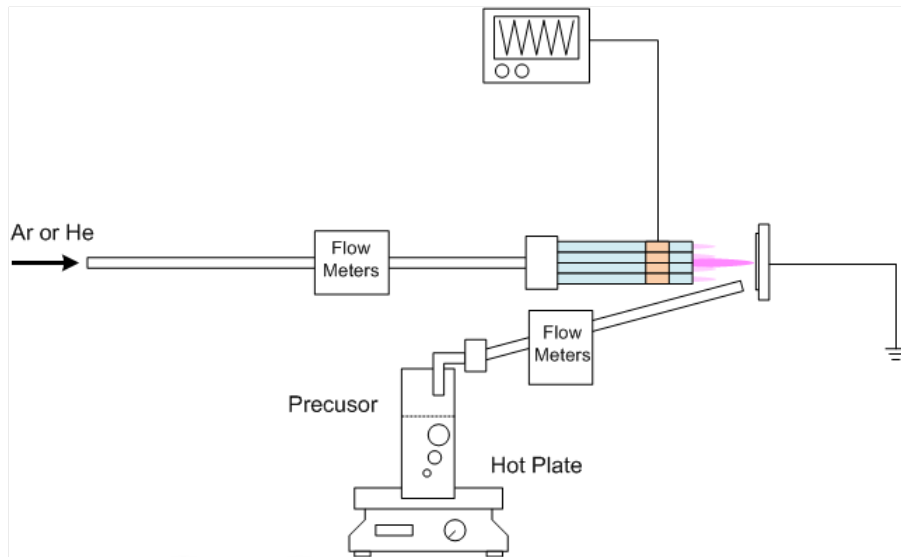


Proposal

Graphene



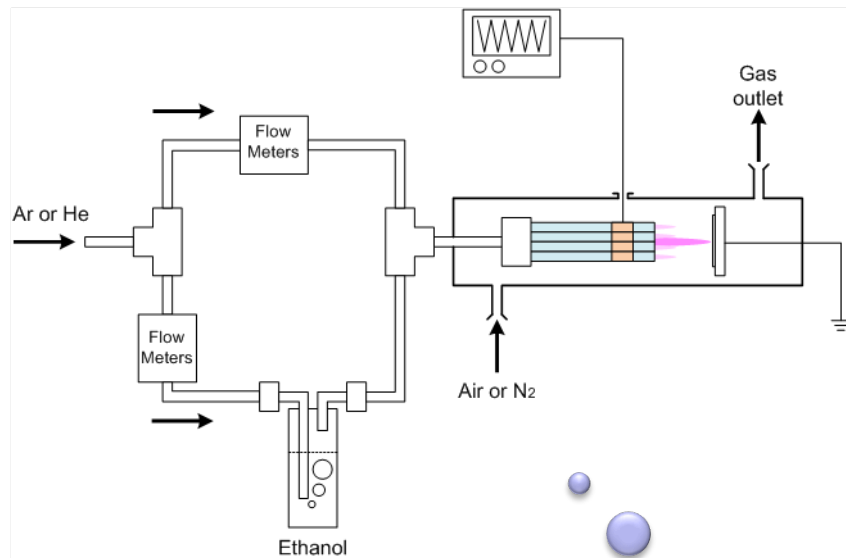
PMMA



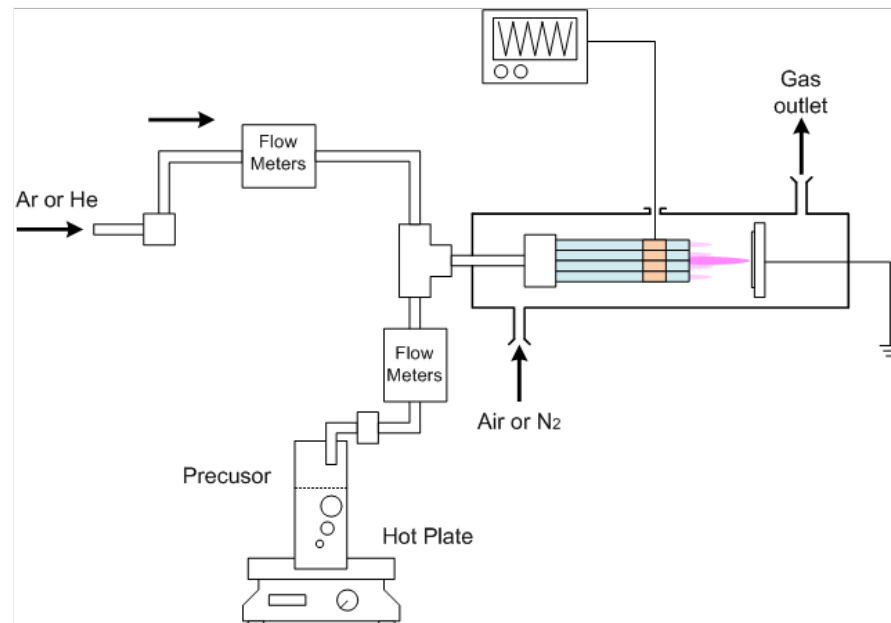
Homogeneous ?
Contaminant ?

Proposal

Graphene



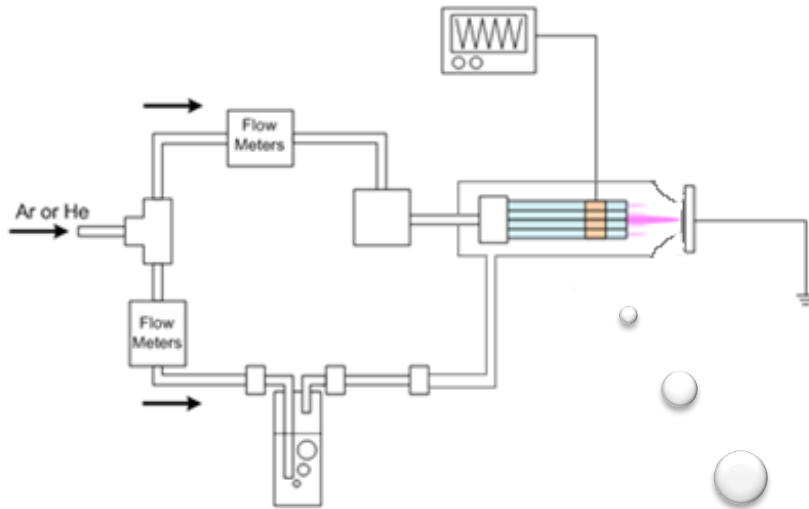
PMMA



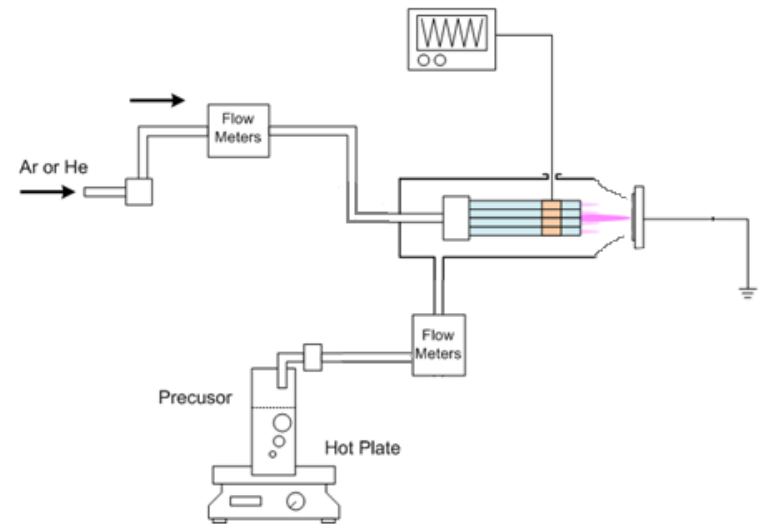
Deposit
back to
tube?

Proposal

Graphene



PMMA



Contact between
electrode and
monomer,
reactive species?

Quality Measurement

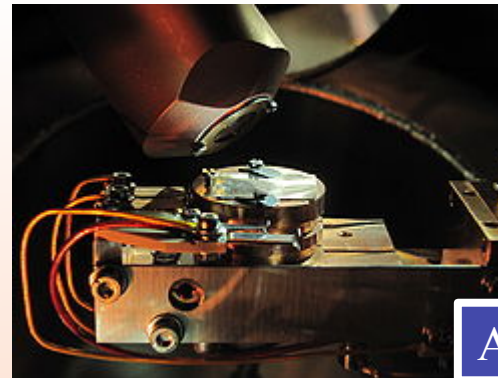


TEM



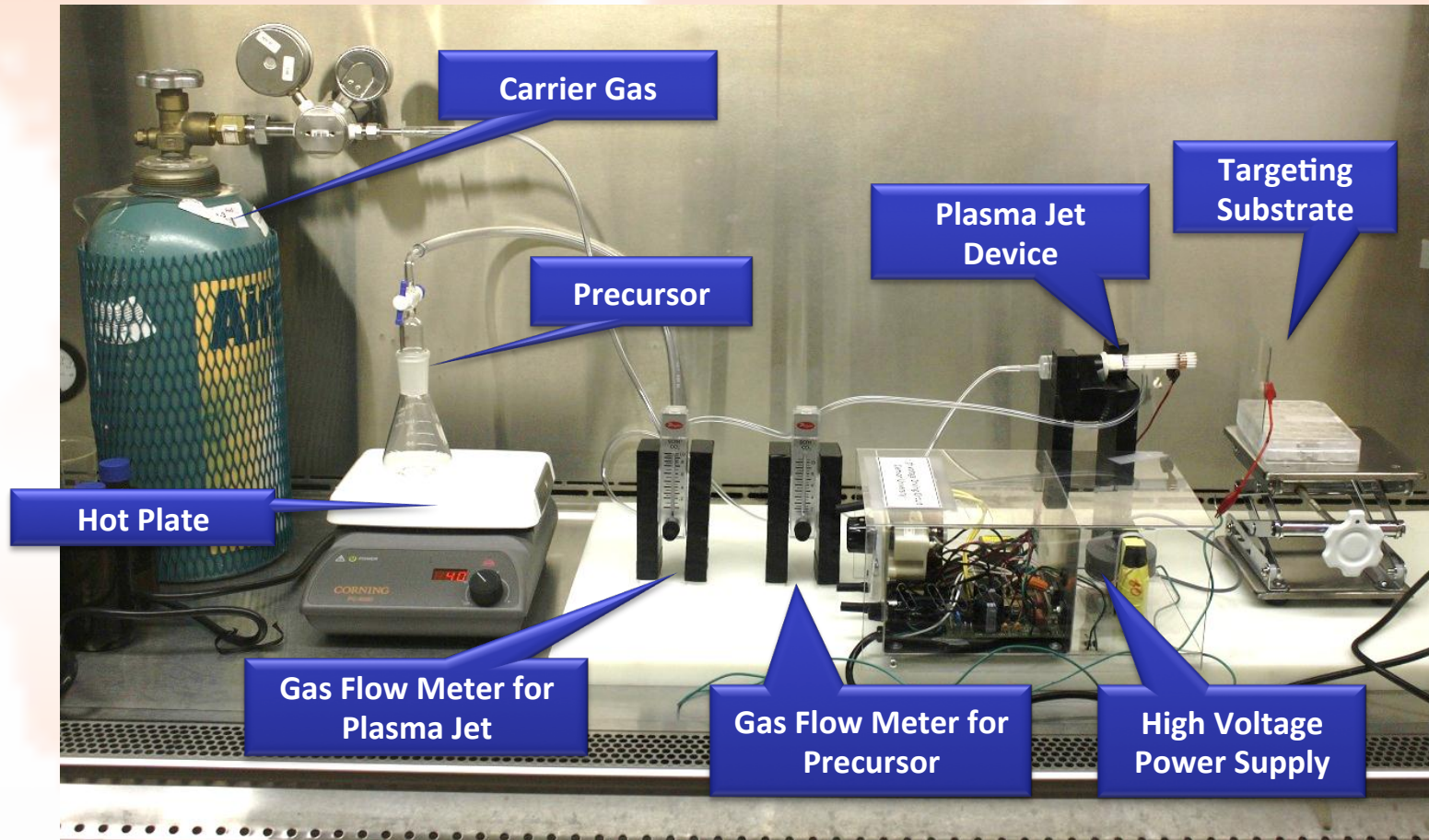
SEM

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AFM

Our Plasma Thin Film Deposition System



Summary

- Thin Film Deposition in generous
- Atmospheric Pressure Plasma Thin Film Deposition
- Research Proposal